ECSE-200 Quiz #1 (13 Jan 2012)

NAME	McGill ID#	

READ each question and its parts carefully before starting. SHOW ALL YOUR WORK. Give units on your answers (where appropriate).

1. Consider the circuit diagram below, representing a battery. Answer the questions.

$$v(t) = 10V + 0.001V/s \times t$$
 $i = 100 \text{mA}$

- a) At what time t is the battery voltage v(t) equal to +12V ? [1pt]
- b) What is the total charge q delivered into the "+" terminal of the battery over the time interval 0s $\leq t \leq 4000$ s? [1pt]
- c) Plot the instantaneous power p(t) absorbed by the battery versus the time t, for the time interval $0s \le t \le 4000s$. Clearly label the axes of your plot with SI units. [3pts]
- d) At what time t is the battery absorbing 1.3W of power? [2pts]
- e) What is the energy absorbed by the battery over the time interval $0s \le t \le 4000s$? [3pts]

a)
$$12V = 10V + \frac{0.001V}{s} \cdot t$$

 $t = \frac{12V - 10V}{0.001V/s} = 2000s$ (+1)

c)
$$P_{abs}^{(t)} = v(t) \cdot i = (10V + \frac{0.001V}{s} \cdot t) \cdot 100mA$$

= $1W + \frac{100\mu W}{s} \cdot t$



Pass work space

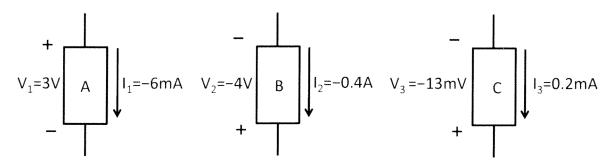
1.4W

4000s

d)
$$1.3W = 1W + \frac{100\mu W}{s} \times t$$
 (+1)
 $t = \frac{1.3W - 1W}{100\mu W/s} = 3000s$ (+1)

e)
$$U_{abs} = \int_{0}^{4000} P_{abs}(t) dt'$$
 [+1]
 $P_{abs}(t') = IW + \frac{100 \mu W}{s} \times t'$ [+1]
... $U_{abs} = \int_{0}^{4000} IW + \frac{100 \mu W}{s} \times t' dt'$
 $= IW. 4000s + \frac{1}{2} \cdot \frac{100 \mu W}{s} \times (4000s)^{2}$
 $= 4.8 \text{ kJ}$ [+1]

2. Consider the circuit diagrams below. Answer the questions, clearly indicating power delivery or absorption.



- a) Do the variables V₁ and I₁ satisfy passive sign convention? [1pt]
- b) How much power is the element A delivering or absorbing? [1pt]
- c) Do the variables V₂ and I₂ satisfy passive sign convention? [1pt]
- d) How much power is the element B delivering or absorbing? [1pt]
- e) Do the variables V₃ and I₃ satisfy passive sign convention? [1pt]
- f) How much power is the element C delivering or absorbing? [1pt]

b)
$$Pabs = V_i \cdot I_i = (3V)(-6mA) = -18mW$$
 absorbing (+1) or +18mW is delivered by A

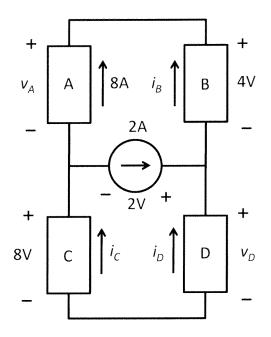


Quiz #2 (20 Jan 2012) ECSE-200

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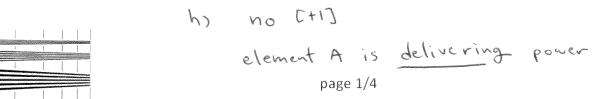
READ each question and its parts carefully before starting. SHOW ALL YOUR WORK. Give units on your answers (where appropriate).

1. Consider the circuit diagram below. Answer the questions.



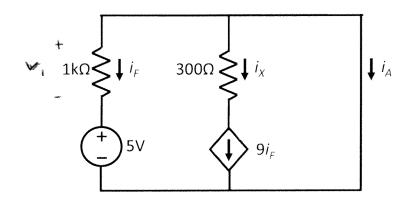
- a) Use KCL to find the value of i_B . [1pt]
- b) Use KCL to find the value of i_C . [1pt]
- c) Use KCL to find the value of i_D . [1pt]
- d) Use KVL to find the value of v_A . [1pt]
- e) Use KVL to find the value of v_D . [1pt]
- f) Element B is a resistor. What is the resistance of element B? [1pt]
- g) Element D is a resistor. What is the resistance of element D? [1pt]
- h) Is it possible that element A is a resistor? (yes or no) [1pt]

f)
$$R_B = -\frac{4V}{-8A} = 0.5 \text{ C(+1)}$$
 g) $R_D = -\frac{10V}{-10A} = 1 \text{ s. C(+1)}$





2. Consider the circuit diagram below. Answer the questions.



- a) What is the value of i_F ? [2pts]
- b) What is the power absorbed by the $1k\Omega$ resistor? [2pts]
- c) What is the power delivered by the independent voltage source? [2pts]
- d) What is the value of i_X ? [2pts]
- e) What is the value of i_A ? [2pts]

a)
$$kVL$$
: $0 = -5V - V_1 + 0$ [+1]
$$V_1 = -5V$$
Ohn: $iF = -\frac{5V}{1kx} = -5mA$ [+1]

b)
$$P_{abs} = i \frac{2}{P} \cdot 1hn$$
 (+1) d) $i_X = 9i_F$ (+1) = -45mA (+1)

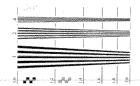
c)
$$P_{del} = (-i_F).5V$$
 [+1]
= 25 mW [+1]

e) KCL:

$$0 = i_F + i_X + i_A \quad [t_1]$$

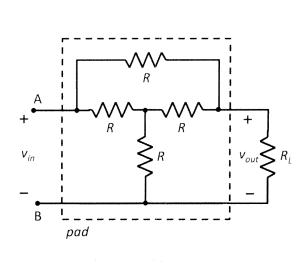
$$i_A = -i_F - i_X$$

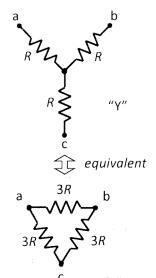
$$= 50 \text{ mA} \quad [t_1]$$



READ each question and its parts carefully before starting. SHOW ALL YOUR WORK. Give units on your answers (where appropriate).

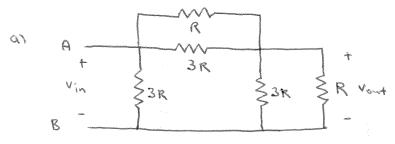
1. Consider the circuit diagram below, including the Y-to- Δ equivalent resistance transformation. The boxed area is known as a "fixed attenuator pad", and is used in volume control circuits. Answer the questions.





a) If $R_L = R$, what is the equivalent resistance between the terminals A and B? [2pts] **HINT:** You may find it useful to use a Y-to- Δ equivalent resistance transformation.

- b) If $R_L = R$, what is the ratio v_{out} / v_{in} ? Your answer should be a number. [2pts]
- c) If $R_L = R = 600\Omega$, and $v_{in} = 2V$, how much power is absorbed by the resistor R_L ? [2pts]
- d) If $R_L = R = 600\Omega$, and $v_{in} = 2V$, how much power is absorbed by the entire circuit of resistors? [2pts]



$$R_{AB} = 3R // (3R//R + 3R//R)$$



$$3R//R = \frac{3R \cdot R}{3R + R} = \frac{3}{4}R$$
 $3R//R + 3R//R = \frac{3}{4}R$

$$3R/1R + 3R/1R = \frac{3}{a}R$$

$$R_{AB} = 3R / \frac{3}{2}R = \frac{3R \cdot \frac{3}{2}R}{3R + \frac{3}{2}R} = R$$
 [+1]

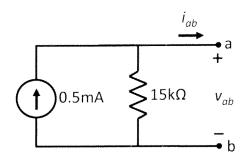
b)
$$\frac{V_{\text{out}}}{V_{\text{in}}} = \frac{3R/IR}{3R/IR + 3R/IR}$$
 voltage dividen
$$= \frac{1}{a} \quad (+2)$$

c)
$$P_{abs} = \frac{v_{out}}{R_L} = \frac{\left(\frac{1}{2}v_{in}\right)^2}{R_L} = \frac{(1V)^2}{600\pi} = 1.667 \text{ mW C+a}$$

d)
$$P_{abs} = \frac{v_{in}^2}{R_{AB}} = \frac{v_{in}^2}{R} = \frac{(2V)^2}{600 \text{ s}} = 6.667 \text{ mW}$$
 C+2]



2. Consider the circuit diagram below. Answer the questions.



- a) An ideal ammeter is connected to terminals a and b. What is the measured value of i_{ab} ? [1pt]
- b) An ammeter with $1k\Omega$ equivalent resistance is connected to terminals a and b. What is the measured value of i_{ab} ? [1pt]
- c) An ideal voltmeter is connected to terminals a and b. What is the measured value of v_{ab} ? [1pt]
- d) You have used a voltmeter connected to terminals a and b, and measure v_{ab} = 6V. What is the equivalent resistance of your voltmeter? [1pts]

$$\dot{v}_{ab} = 0.5 \text{ mA} \cdot \frac{15 \text{ kn}}{1 \text{ kn} + 15 \text{ kn}}$$

$$= 0.4688 \text{ mA} \quad \text{C+1}.$$

$$v_{ab} = 0.5 \text{mA} \cdot 15 \text{ks}$$

= 7.5 V C+13

$$R//15hx = \frac{6V}{0.5mA} = 10hx$$

$$\frac{1}{R} + \frac{1}{15kn} = \frac{1}{12kn}$$

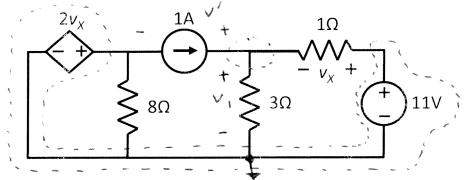
$$R = \left(\frac{1}{126n} - \frac{1}{156n}\right)^{-1}$$

ECSE-200 Quiz #4 (3 Feb 2012)

NAME	McGill ID#
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READ each question and its parts carefully before starting. SHOW ALL YOUR WORK. Give units on your answers (where appropriate).

1. Consider the circuit diagram below. Answer the questions.

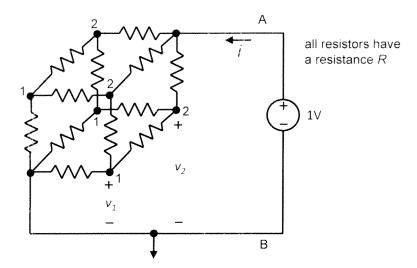


- a) How many supernodes are there in the circuit? How many nodes (which are not part of a supernode) are there in the circuit? [2pts]
- b) What is the voltage across the 3Ω resistor? Be sure to clearly define your voltage variable on the diagram. [3pts]
- c) How much power does the 1A current source deliver or absorb? [2pts]

b)
$$O = -1A + \frac{V_1}{3n} + \frac{V_1 - 11V}{1n}$$
 C+2)

$$v' = v_1 - 2v_x = 9v - 4v = 5v$$

2. In this problem, you will find the equivalent resistance for a cube of resistors. Each resistor has a resistance *R*. Answer the questions.



By symmetry, it follows that each node labeled 1 is equivalent, having the same potential v_1 with respect to reference. It also follows that each node labeled 2 is equivalent, having the same potential v_2 with respect to reference.

- a) What is the node equation for v_1 ? [2pts] **HINT**: All nodes labeled 1 have the same node equation.
- b) What is the node equation for v_2 ? [2pts] **HINT**: All nodes labeled 2 have the same node equation.
- c) What are the values of v_1 and v_2 ? [2pts]
- d) What is the current i? Your answer will depend on R. [2pts]
- e) What is the equivalent resistance R_{eq} of the cube of resistors with respect to terminals A and B? [2pts]

a)
$$O = \frac{V_1}{R} + \frac{V_1 - V_2}{R} + \frac{V_1 - V_2}{R}$$
 [+2]

b)
$$0 = \frac{V_{a} - V_{1}}{R} + \frac{V_{a} - V_{1}}{R} + \frac{V_{a} - 1V}{R}$$
 (+2]



d)
$$\hat{c} = 3 \cdot \frac{V_i}{R} = \frac{6}{5} \frac{V}{R} = \frac{1.2V}{R}$$
 [+2]

or $i = 3 \cdot \frac{(1V - V_a)}{R}$

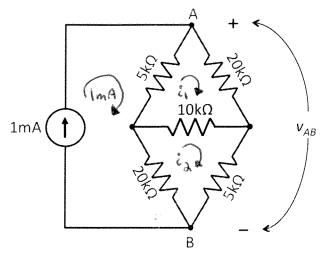
e)
$$Req = \frac{IV}{\dot{c}} = \frac{IV}{(I.aV/R)} = \frac{5}{6}R$$
(+1)

ECSE-200 Quiz #5 (10 Feb 2012)

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READ each question and its parts carefully before starting. SHOW ALL YOUR WORK. Give units on your answers (where appropriate).

1. Consider the circuit diagram below. This circuit is a resistance bridge. Answer the questions.



- a) Which technique, nodal or mesh analysis, gives fewer equations to solve for the circuit? [1pt]
- b) Use the technique that you identified in a) to solve for the circuit variables (ie. mesh currents or node voltages). Clearly identify your variables in the diagram. [2pts]
- c) What is the value of the voltage v_{AB} ? [1pt]
- d) What is the equivalent resistance of the resistor network between terminals A and B? [2pts]
- e) What is the equivalent resistance of the resistor network between terminals A and B if an open circuit replaces the $10k\Omega$ resistor? [2pts]
- f) What is the equivalent resistance of the resistor network between terminals A and B if a short circuit replaces the $10k\Omega$ resistor? [2pts]

b)
$$0 = 5kn(i_1 - lmA) + a0kn-i_1 + 10kn(i_1 - i_a)$$

 $0 = a0kn(i_a - lmA) + 10kn(i_a - i_1) + 5kn-i_a$

$$5 = 35i_1 - 10i_2$$

 $20 = -10i_1 + 35i_2$

$$i_1 = \begin{vmatrix} 5 & -10 \\ 20 & 35 \end{vmatrix} = 0.333 \text{ mA}$$
 (+13)

$$i_{a} = \frac{\begin{vmatrix} 35 & 5 \\ -10 & a_{0} \end{vmatrix}}{\begin{vmatrix} 35 & -10 \\ -10 & 35 \end{vmatrix}} = 0.666 \text{ mA}$$
 C+17



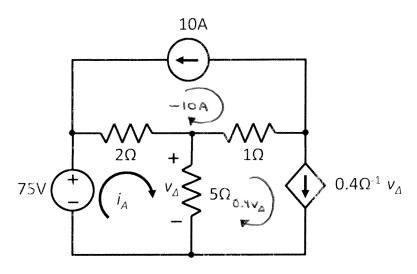
d)
$$R_{AB} = \frac{V_{AB}}{I_{MA}}$$
 (+1)
$$= \frac{IOV}{I_{MA}} = IO kn C+1)$$

(+1)
$$\frac{1}{2000}$$
 $\frac{1}{2000}$ $\frac{1}{2000}$

f)
$$= \begin{cases} shn & saohn \\ shn & = 8hn \end{cases}$$

$$= 8hn \quad CHI$$

2. Consider the circuit below. Answer the questions.



- a) What is the KVL equation for the mesh current i_A ? [3pts]
- b) What is the value of the mesh current i_A ? [1pt]
- c) What is the value of the control variable v_{Δ} ? [1pt]
- d) How much power does the 5Ω resistor absorb? [1pt]

a)
$$0 = -75V + an \cdot (i_A + 10A) + 5n (i_A - 0.4v_a)$$

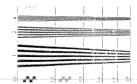
(+17 (+13 (+13

b)
$$V_{\Delta} = 5 \pi \cdot (i_{A} - 0.4 V_{\Delta})$$
 $v_{\Delta} = \frac{5}{3} \pi \cdot i_{A}$

$$O = -75 V + \lambda \pi (i_{A} + 10A) + 5 \pi (i_{A} - 0.4 \cdot \frac{5}{3} \cdot i_{A})$$

$$i_{A} = \frac{75 - 20}{2 + 5 - 10/3} A = 15 A C+13$$

d)
$$P_{abs} = \frac{v_{\Delta}^2}{5n} = \frac{(25v)^2}{5n} = 125W$$
 C+13

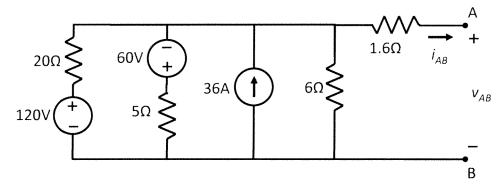


ECSE-200 Quiz #6 (17 Feb 2012)

NAME	McGill ID#	

READ each question and its parts carefully before starting. SHOW ALL YOUR WORK. Give units on your answers (where appropriate).

1. Consider the circuit diagram below. Answer the questions.



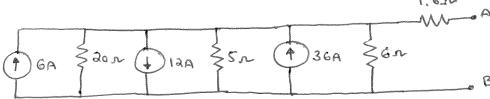
- a) What property must a circuit have in order for the principle of superposition to apply? [1pt]
- b) What is Thévenin's theorem? (one sentence is sufficient) [1pt]
- c) Find the Thévenin equivalent circuit with respect to the terminals A and B. Clearly label the terminals A and B on your equivalent circuit. [3pts]

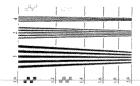
NOTE: There are numerous ways to solve this problem.

- d) Draw the i_{AB} - v_{AB} diagram for the circuit above, clearly identifying the short-circuit current and open-circuit voltage on your diagram. [3pts]
- e) Use a source transformation on the Thévenin equivalent circuit to find the Norton equivalent circuit with respect to the terminals A and B. [2pts]

b) Any two-terminal circuit composed of independent sources, dependent sources and ideal resistors is equivalent to a Thévenin equivalent circuit. [+1]

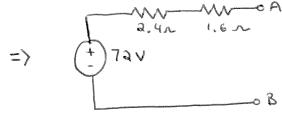
Use source transformations: ()





130A \$ 2.4n

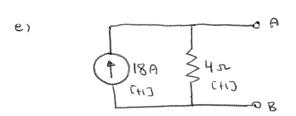
work space



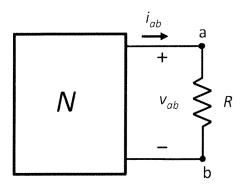
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72V CHIS B

Ett for Thévenin circuit form]



2. Consider the circuit below. Answer the questions.



The circuit *N* is known to be composed of independent sources, dependent sources and ideal resistors.

When the resistance $R = 25\Omega$, it is found that 250mW of power is absorbed by the resistor R.

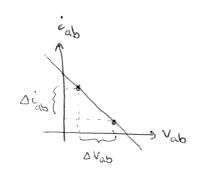
When the resistance $R = 125\Omega$, it is found that 312.5mW of power is absorbed by the resistor R.

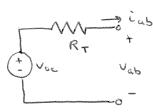
- a) What is the Thévenin resistance of N? [6pts]
- b) What is the open-circuit voltage of N? [2pts]

$$R = 25n \quad P = 250mW \qquad \frac{V_1^2}{25n} = 250mW \qquad v_1 = 2.5V \qquad i_1 = \frac{2.5V}{25n} = 100mA \qquad cti)$$

$$R = 125n \quad P = 312.5mW \qquad \frac{V_1^2}{125n} = 312.5mW \qquad v_2 = 312.5mW \qquad v_3 = 6.25V \qquad i_4 = \frac{6.25V}{125n} = 50mA \qquad cti)$$

$$V_1 = 6.25V \qquad i_4 = \frac{6.25V}{125n} = 50mA \qquad cti)$$

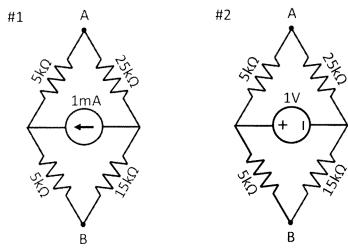




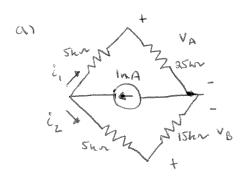
$$\frac{1}{100} - R_T = \frac{\Delta V_{ab}}{\Delta i_{ab}} = \frac{V_1 - V_2}{i_1 - i_2} = \frac{2.5V - 6.25V}{100 \text{ mA} - 50 \text{ mA}} = -75 \text{ Jz}$$

READ each question and its parts carefully before starting. SHOW ALL YOUR WORK. Give units on your answers (where appropriate). THINK ABOUT YOUR TECHNIQUE BEFORE YOU SOLVE!

1. Consider the circuit diagrams below. Answer the questions.

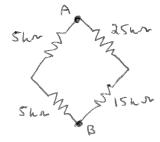


- a) What is the Thévenin equivalent of circuit #1 with respect to the terminals A and B? [3pts]
- b) What is the maximum power that circuit #1 can deliver to an optimally chosen load resistor connected across terminals A and B? [2pts]
- c) What is the Thévenin equivalent of circuit #2 with respect to the terminals A and B? [3pts]
- d) What is the maximum power that circuit #2 can deliver to an optimally chosen load resistor connected across terminals A and B? [2pts]



Find
$$V_{0c}$$
 and R_{TM} . (+1)
$$\dot{c}_{1} = ImA \cdot \frac{(5+15)}{(5+15) + (5+25)} = 0.400 mA$$

$$\dot{c}_{2} = ImA \cdot \frac{(5+25)}{(5+25) + (5+15)} = 0.600 mA$$



b)
$$P_{\text{max}} = \frac{V_{\text{oc}}}{\lambda} \cdot \frac{i_{\text{sc}}}{\lambda}$$

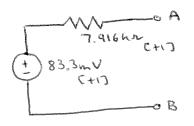
$$= \frac{V_{\text{oc}}^2}{4R_{\text{TH}}}$$

$$= 31.25 \text{ mW} \text{ CHI}$$

Sun
$$V_A = IV \cdot \frac{25}{5+25} = 0.833V$$
 Find voc and R_{TH} .

 $V_B = IV \cdot \frac{15}{5+5} = 0.750V$

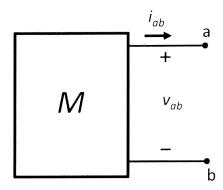
Show $V_B = IV \cdot \frac{15}{5+5} = 0.750V$
 $V_{OC} = V_A - V_B = 83.3 \text{ mV}$



d)
$$P_{\text{max}} = \frac{V_{\text{OC}}}{2} \cdot \frac{\hat{c}_{\text{SC}}}{2}$$

$$= \frac{V_{\text{OC}}}{4R_{\text{Ty}}} \quad \text{(+1)}$$

2. Consider the circuit below. Answer the questions.



The circuit M is known to be composed of independent sources, dependent sources and ideal resistors.

When an ammeter with $15k\Omega$ internal resistance is connected across terminals a and b, a current i_{ab} =3mA is measured.

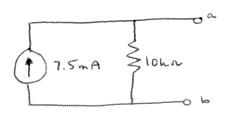
When an ammeter with $5k\Omega$ internal resistance is connected across terminals a and b, a current i_{ab} =5mA is measured.

- a) What is the Norton equivalent circuit of M? [5pts]
- b) What is the maximum power that the circuit M can deliver to an optimally chosen load resistor connected to terminals a and b? [2pts]
- c) What is the maximum power that the circuit M can deliver to an optimally chosen load resistor connected to terminals a and b if it is also required that $v_{ab} \ge 60$ V? [2pts]

$$\begin{cases}
V_{ab} = V_{oc} - i_{ab}R_{T} & \therefore R_{T} = -\frac{\Delta V_{ab}}{\Delta i_{ab}} = -\frac{(45V - \lambda 5V)}{(3mA - 5mA)} = 10 \text{ kn CHD} \\
i_{ab} = i_{sc} - \frac{V_{ab}}{R_{T}} & i_{sc} = i_{ab} + \frac{V_{ab}}{R_{T}} = 3mA + \frac{45V}{10 \text{ kn}} = 7.5 \text{ mA CHJ}
\end{cases}$$

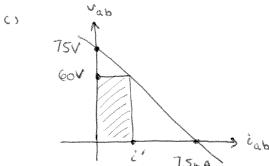
$$R_{T} = -\frac{\Delta Vab}{\Delta iab} = -\frac{(45V - 25V)}{(3mA - 5mA)} = 10 \text{ km CHD}$$

$$i_{SC} = i_{ab} + \frac{v_{ab}}{R_T} = 3_{mA} + \frac{45V}{10_{km}} = 7.5_{mA} C+1$$





b)
$$P_{max} = \frac{v_{oc}}{a} \cdot \frac{i_{sc}}{a} = \frac{i_{sc} \cdot R_T}{4} = 140.6 \text{ mW}$$
 (+1)



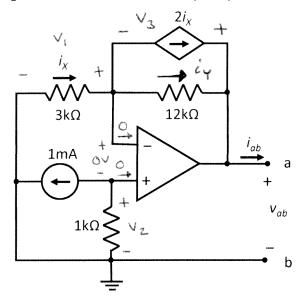
$$\frac{i'}{7.5\text{mA}} = \frac{75\text{V} - 60\text{V}}{75\text{V}}$$

$$i' = 1.5\text{mA}$$

NAME	McGill ID#	!

READ each question and its parts carefully before starting. SHOW ALL YOUR WORK. Give units on your answers (where appropriate). THINK ABOUT YOUR TECHNIQUE BEFORE YOU SOLVE!

1. Consider the circuit diagram below. Assume ideal op-amp behaviour. Answer the questions.



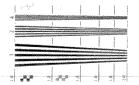
- a) What is the value of the current i_X ? [3pts]
- b) What is the value of v_{ab} if a $3k\Omega$ resistor is connected across the terminals a and b? [3pts]
- c) What is the value of i_{ab} if a $3k\Omega$ resistor is connected across the terminals a and b? [2pts]
- d) What is the Thévenin equivalent of the circuit above with respect to the terminals a and b? [1pt]

a)
$$V_{a} = -ImA \cdot Ikx = -IV \text{ C+I}$$

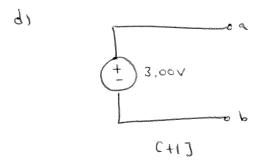
$$V_{1} = V_{2} = -IV \text{ C+I}$$

$$\dot{c}_{x} = -\frac{V_{1}}{3kx} = -\frac{(-IV)}{3kx} = 0.333 \text{ mA C+I}$$

b) KCL:
$$O = -ix + 2ix + iy$$
 (cta)
or: $O = \frac{V_1}{3kn} + 2ix + \frac{V_1 - V_{AB}}{12kn}$

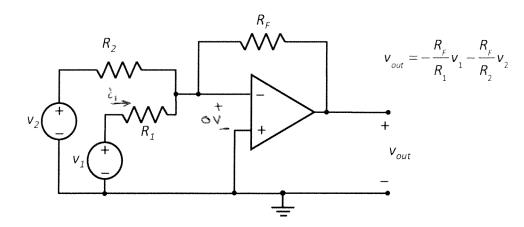


c)
$$i_{ab} = \frac{v_{ab}}{3hn}$$
 (+1)
$$= \frac{3.00V}{3hn} = ImA$$
 (+1)



 $R_T = 0$ since V_{ab} is independent of \tilde{c}_{ab} .

2. Consider the circuit below. Assume ideal op-amp behaviour. Answer the guestions.



You are to design the above circuit to implement the function $v_{out} = -10 \ v_1 - 20 \ v_2$. It is also desired that the source v_1 delivers $5\mu W$ when $v_1 = 100 \text{mV}$.

- a) What is the value of R_1 , R_2 and R_F ? [6pts]
- b) Assume that the power supplies to the op-amp are +10V and -10V. If v_1 = 0V, over what range of input voltage v_2 will the output voltage be given by v_{out} = -20 v_2 ? (Equivalently, over what range of input voltage v_2 will the op-amp behaviour be ideal?) [2pts]
- c) Give one reason why negative feedback is used in op-amp circuits. [1pt]

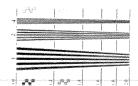
a)
$$i_1 = V_1 / R_1$$
 $P_{del} = V_1 \cdot i_1 = V_1^2 / R_1$... $R_1 = \frac{V_1^2}{P_{del}}$ (+1)

 $= \frac{(100 \text{mV})^2}{S_{\text{MW}}} = dk R$ (+1)

Since $V_{\text{Out}} = -\frac{R_F}{R_1} \cdot V_1 - \frac{R_F}{R_2} V_2$
 $= -10 \ V_1 - 20 V_2$

We have: $\frac{R_F}{R_1} = 10$ (+1) $R_F = 10 R_1 = 20 k R$ (+1)

also: $\frac{R_F}{R_2} = 20$ (+1) $R_2 = \frac{R_F}{20} = 1 k R$ (+1)



b) $-10V < -20V_2 < +10V$ [+1] 0.5V > V_2 > -0.5V [+1]

programmable output

output independent / weakly dependent on open-loop gain

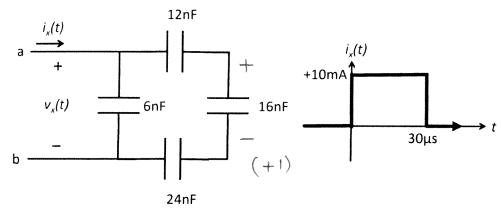
(+1) for any

ECSE-200 Quiz #9 (16 Mar 2012)

NAME	McGill ID#	ŧ

READ each question and its parts carefully before starting. SHOW ALL YOUR WORK. Give units on your answers (where appropriate). THINK ABOUT YOUR TECHNIQUE BEFORE YOU SOLVE!

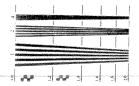
1. Consider the circuit and plot below. The capacitors are storing zero energy at t=0. Answer the questions.



- a) Give one physical reason why voltage is continuous on a capacitor. [1pt]
- b) What is the equivalent capacitance between terminals a and b? [2pts]
- c) What is the value of $v_x(t)$ at $t = 30\mu s$? [2pts]
- d) What is the charge separation on the 6nF capacitor at $t = 30\mu$ s? Indicate the polarity of the charge separation on the circuit diagram. [2pts]
- e) What is the charge separation on the 16nF capacitor at $t = 30\mu$ s? Indicate the polarity of the charge separation on the circuit diagram. [3pts]

b)
$$\alpha = \frac{1}{6nF} + \frac{1}{16nF} + \frac{1}{16nF} + \frac{1}{24nF}$$

 $b = \frac{1}{5.33nF} + \frac{1}{6nF} + \frac{1}{24nF}$
 $c' = 5.33nF + 6nF = 11.33nF(+1)$



(c)
$$i = C \frac{dV}{dt}$$
 $\Rightarrow V(30\mu S) = \frac{1}{C} \int_{c}^{30\mu S} \frac{30\mu S}{c(t)} dt$ $(+1)$

$$= \frac{1}{11.33nF} \int_{c}^{30\mu S} \frac{10mA}{c} dt = \frac{1}{11.33nF} \left[10mA \times t \right]_{0}^{30\mu S}$$

$$= 26.47V (+1)$$

d)
$$Q = CV (+1)$$

 $Q = 6 nF \times 26.47V = 158.82 nC (+1)$

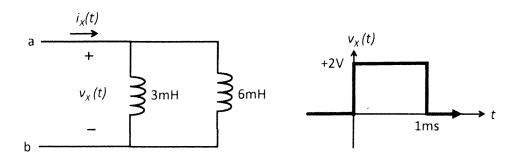
e) Total Charge =
$$G_{qV} = 11.3 \, \text{nF} \times 26.47 \, \text{V} = 3 \times 10^7 \, \text{C} = 0.3 \, \mu \, \text{C}$$

$$(+1)$$

$$q_{16nF} = Q - Q_{6nF}$$

$$= 0.3 \mu C - 0.15882 \mu C = 0.14118 \mu C (+1)$$
$$= 141.18 \mu C (+1)$$

2. Consider the circuit and plot below. The inductors are storing zero energy at t=0s. There is no mutual inductance between the inductors. Answer the questions.



- a) Give one physical reason why current is continuous in an inductor. [1pt]
- b) What is the equivalent inductance between terminals a and b? [2pts]
- c) What is the value of $i_x(t)$ at t = 1ms? [2pts]
- d) What is the energy stored in the 3mH inductor at t=0.5ms? [2pts]
- e) What is the energy stored in the 3mH inductor at t=1ms? [2pts]

a) Conservation of Energy (+1)
b)
$$\frac{1}{\text{Leq}} = \frac{1}{3mH} + \frac{1}{6mH}$$
 (+1)
 $\frac{1}{\text{Leq}} = 2mH$ (+1)

Leq =
$$2mH$$
 (+1)
 $V = L \frac{di}{dt} \rightarrow i(t) = \frac{1}{L} \int V(t) dt$ (+1)
 $i(t) = \frac{1}{2mH} \int_{0}^{1mS} 2dt = \frac{1}{2mH} \left[2t\right]_{0}^{1mS} = 1A$ (+1)

d)
$$U = \frac{1}{2} Li^{2}$$
 (+1)
 $c(0.5ms) = \frac{1}{3mH} \left[2t \right]_{0}^{0.5ms} = 0.333 A$
 $U = \frac{1}{2} X 3mH \times 0.333^{2} = 0.1667 mJ(+1)$

e)
$$U = \frac{1}{2} Li^{2} (+1)$$

 $i(1ms) = \frac{1}{3mH} [2t]_{0} = 0.666 A$
 $U = \frac{1}{2} \times 3mH \times 0.666^{2} = 0.666 mJ (+1)$



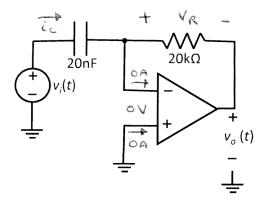


ECSE-200 Quiz #10 (23 Mar 2012)

NAME AV	SWER	- KEY	McGill ID#	
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READ each question and its parts carefully before starting. SHOW ALL YOUR WORK. Give units on your answers (where appropriate). THINK ABOUT YOUR TECHNIQUE BEFORE YOU SOLVE!

1. Consider the circuit below. Assume ideal op-amp behaviour. Answer the questions.



- a) Express the output voltage $v_o(t)$ in terms of the input voltage $v_i(t)$. [3pts]
- b) If the input voltage $v_i(t)=1V\cos(2\pi ft)$ with f=1kHz = 1000s⁻¹, what is the output voltage $v_o(t)$? [2pts]
- c) If the input voltage $v_i(t)=1V\cos(2\pi ft)$ with $f=1kHz=1000s^{-1}$ (as above), what is the **maximum** instantaneous power absorbed by the resistor? [2pts]
- d) The power supply voltages to the op-amp are +10V and -10V. If the input is $v_i(t)=1V\cos(2\pi ft)$, what is the maximum frequency f for which the op-amp will still operate as an ideal op-amp? [1pt]

a)
$$i_c = c \frac{dv_i}{dt}$$
 (40) $kv(t) = 0 = V_i(t) - V_o(t) - R(dV_{io} - V_{ill})$

$$V_R = R(dV_i)$$

$$= V_o(t) = -R(dV_{io}) C_{to}$$

$$= -4x_{io} \frac{dv_i}{dt} C_{to}$$

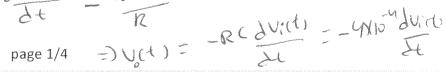
OR Using KCl

$$= \sum_{i} -cdv_{i} - cd(0-v_{i},0) - cdv_{i}(t)$$

$$i_{R} = \frac{O-V_{0}(t)}{R} - \frac{V_{0}(t)}{R}$$

$$V_{0}(t) = \frac{V_{0}(t)}{R}$$

$$= \int_{-\infty}^{\infty} \frac{dv_{i}(t)}{dt} = \frac{v_{i}(t)}{R}$$





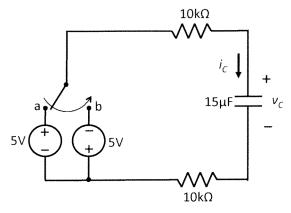
$$\frac{dv_i(t)}{dt} = -2\pi f \sin(2\pi f t) \quad (+1)$$

()
$$P = \frac{\sqrt{2}}{R}$$
 (+1)

d) max
$$V_0(t) = |OV = (0.4m)(2\pi f)$$

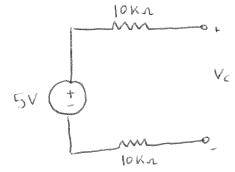
=) $f = \frac{10}{(0.4m)(2\pi)} = 3.978.8 Hz (+1)$

- 2. Consider the circuit below. The capacitor is in dc steady state for t < 0, with the switch in position
- a. At t=0s, the switch moves instantaneously from position a to position b. Answer the questions.

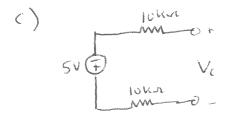


- a) What is the dc steady state value of $v_c(t)$ for t < 0? [1pt]
- b) What is $v_c(0+)$? [2pts]
- c) What is the dc steady state value of $v_c(t)$ as $t \to \infty$? [1pt]
- d) What is the time constant τ of this RC circuit? [2pts]
- e) It can be shown that $v_c(t) = c_1 + c_2 \exp(-t/\tau)$ for t > 0. What are the constants c_1 and c_2 ? [2pts]
- f) At what time t does $v_c(t) = 0V$? [1pt]
- g) What is the current $i_c(t)$ for t > 0? [2pts]

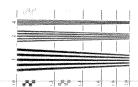
a)



b) $V_c(0-) = V_c(0+)$ Continuity of capacitor voltage [+1]



$$V_c(t)$$
 for $t \rightarrow \infty$
 $V_c = -5V$ [+1]



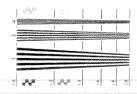
$$R_{\tau} = 10 \text{kn} + 10 \text{kn} = 20 \text{kn}$$
 [+1]
 $C = 15 \text{MF}$
=) $T = (20 \text{kn}) (15 \text{MF})$
= 0.3 5 [+1]

e)
$$C_1 = V(\infty) = -5V$$
 (+1)
 $C_2 = V(0+) - V(\infty) = 5 - (-5) = 10V(+1)$

F)
$$V_{c}(t) = C_{1} + C_{7} \exp(-\frac{t}{2}h)$$

 $= -5 + 10 \exp(-\frac{t}{2}h)$
 $V_{c}(t) = 0 \Rightarrow -5 + 10 \exp(-\frac{t}{2}h) = 0$
 $\exp(-\frac{t}{2}h) = \frac{t}{2}h$
 $-\frac{t}{2}h = 0.30795$ [+1]

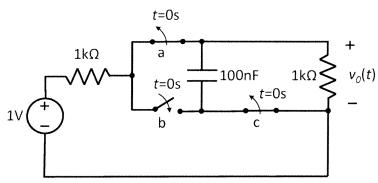
9)
$$i_{i} = C \frac{dV_{cl}(t)}{dt}$$
 (+1)
= $15MF \frac{d[-S+10eAp(\frac{1}{63})]}{dt}$
= $15MF[\frac{10}{63}eAp(-\frac{1}{63})]$
= $-5\times10^{-9}eXp(-\frac{1}{63})A[+1]$



NAME	McGill ID#	

READ each question and its parts carefully before starting. SHOW ALL YOUR WORK. Give units on your answers (where appropriate). THINK ABOUT YOUR TECHNIQUE BEFORE YOU SOLVE!

1. Consider the circuit below. The circuit is in dc steady state for t < 0, with switch a closed, switch b opened, and switch c closed. At t = 0, switch a opens, switch b closes, and switch c opens. Answer the questions.



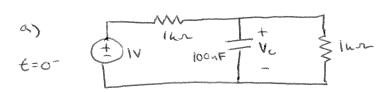
a) How much energy is stored in the capacitor at t = 0? [2pts]

HINT: You may find it useful to draw the circuit for t < 0.

b) What is $v_0(0+)$? [1pt]

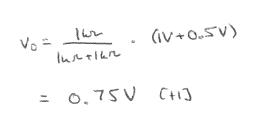
HINT: You may find it useful to draw the circuit for t = 0+.

- c) What is $v_0(\infty)$? [1pt]
- d) What is the time constant τ for the evolution of $v_0(t)$ for t > 0? [2pts]
- e) What is $v_0(t)$ for t > 0? [3pts]

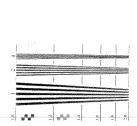


$$V_c = IV \cdot \frac{Ikn}{Ikn+Ikn} = 0.5V CHI$$

$$U = \frac{1}{4}CV_c^2 = IQ.5 nJ CHIJ$$



Vc(0+) = Vc(0-) = 0.5V

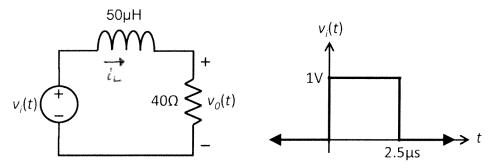


e)
$$V_0(0+) = 0.75V$$
 $V_0(a) = 0V$ $C = 0.2ms$

$$V_0(+) = V_0(a) + (V_0(0+) - V_0(a)) \exp(-t/2) \quad (+1)$$

$$= 0.75V \exp(-t/0.2ms) \quad (+2)$$

2. Consider the circuit and plot below. The inductor is in dc steady state for t < 0. Answer the questions.

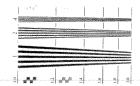


- a) What is $v_0(0+)$? [1pt]
- b) What is $v_0(2.5 \mu s-)$? [1pt]
- c) What is $v_0(2.5\mu s+)$? [1pt]
- d) What is $v_0(\infty)$? [1pt]
- e) What is the time constant τ of this circuit? [1pt]
- f) What is $v_0(t)$ for $0 < t < 2.5 \mu s$? [3pts]
- g) What is $v_0(t)$ for 2.5 μ s < t? [3 μ ts]

Vo (D) assuming no further transients = IV

$$\gamma = \frac{L}{R} = \frac{50\mu H}{40R} = 1.25\mu s \quad [+1]$$

$$V_{0}(t) = V_{0}(\theta) + (V_{0}(0t) - V_{0}(\theta)) \exp(-t/t)$$
 [H]
= $1V - 1V \exp(-t/125\mu s)$ [H]



For
$$t < 2.5 \mu s$$
: $V_0(2.5 \mu s t) = 0.865 V$ $V_0(4) = 0 V$ $V_0 = 1.25 \mu s$ (+1)
 $V_0(t) = V_0(a) + (V_0(2.5 \mu s t) - V_0(a)) \exp(-(t - 2.5 \mu s)/V)$ (+1)
 $= 0.865 V \exp(-(t - 2.5 \mu s)/1.25 \mu s)$ (+1)